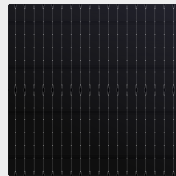
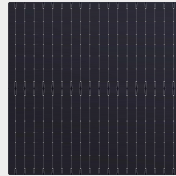


KEY FEATURES

-  High Photoelectric Conversion Efficiency
-  Higher Power Generation
-  Excellent Resistance to Hidden Cracks
-  Higher Efficiency in Power Generation



Front



Back

Size : 210mm*210mm±0.25mm

Thickness : 130±13μm

Solderability : ≥0.9N/mm

The results may vary depending to DS,welding methods and conditions.

Technical Data And Design

Power: -0.25%/K

Voltage: -0.3 %/K

Current: +0.045%/K

Front (-): 18*0.05mm busbar(silver),178 fingers,blue anti-reflection film(siliconoxynitride)(nitrousoxide)

Back (+): 18*0.05mm busbar(silver),198 fingers,blue anti-reflection film (siliconnitride)

Front Electrical Performance Parameters (Standard Test Conditions: 1000 W/m², AM1.5, 25°C)

No.	Eta (%)	Pmpp(W)	Uoc(V)	Isc(A)	FF (%)
1	25.5	11.24	0.735	18.333	83.44
2	25.4	11.20	0.734	18.289	83.40
3	25.3	11.16	0.734	18.238	83.37
4	25.2	11.11	0.733	18.180	83.34
5	25.1	11.07	0.733	18.131	83.31
6	25.0	11.02	0.732	18.074	83.28
7	24.9	10.98	0.732	18.025	83.24
8	24.8	10.94	0.731	17.970	83.20
9	24.7	10.89	0.731	17.917	83.16
10	24.6	10.85	0.731	17.866	83.10
11	24.5	10.80	0.730	17.814	83.04
12	24.4	10.76	0.730	17.767	82.99
13	24.3	10.72	0.729	17.716	82.93
14	24.2	10.67	0.729	17.664	82.88

Iv Curve

